V ibrational inelastic scattering e ects in m olecular electronics

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A bstract

We describe how to treat the interaction of travelling electrons with localised vibrational modes in nanojunctions. We present a multichannel scattering technique which can be applied to calculate the transport properties for realistic systems, and show how it is related to other methods that are useful in particular cases. We apply our technique to describe recent experiments on the conductance through molecular junctions.

Introduction

E lectronic transport through nanoscale system s connected to external electrodes exhibits a number of new features when compared to conduction through m acroscopic system s. Prim ary am ong these is the importance of local interactions { including C oulom b interactions between the electrons, and scattering from localised atom ic vibrations. C rudely speaking these e ects are m ore important in nanoscale system s because the electronic probability density is concentrated in a sm all region of space; norm al screening m echanism s are then ine ective.

Perhaps the most extrem e instance of nanoscale transport is where an electrical connection is form ed through a single molecule. This paper describes how to approach electron transport in such systems theoretically. Our aim is to convince the reader that in many cases the local interaction is not a small perturbation which can be added in later instead, it plays the principal role in determ ining the transport physics. In order to treat it, we need to understand the role of the localm olecular properties dom inated by these local interactions in scattering currentcarrying electrons as they pass by. A swell as determ ining the current ow, the interactions are then responsible for other important phenom ena such as local heating.

Such a situation is already familiar in the physics of transport through sem iconductor quantum dots [1], where local C oulom b interactions produce C oulom b blockade (regions of very low conductance where changes in the charge state of the dot are energetically forbidden) and the K ondo e ect (where the local spin of the dot electrons is screened by the conducting carriers). But the situation in m olecules, where the length scales are sm aller and the electronic energy scales are correspondingly larger, is only now being studied.

If the (three-dimensional) extent of an electronic wavepacket is L, the C oulomb interaction between electrons scales as L¹, while the energy arising from short-range interactions with lattice vibrations scales as L³ [2]. We m ight therefore expect the electron-lattice interactions to

dom inate for single m olecules where L is small, and indeed their signatures have been observed in several recent experiments with single m olecules (or small numbers) [3, 4, 5, 6]. These experiments include inelastic electron tunneling spectroscopy (IETS) of small m olecules adsorbed on surfaces [3], studies of m olecular-scale transistors [4], and experiments on m olecular junctions m ade of alkyl or -conjugated m olecular wires [5] or alkanedithicli self-assem bled m onolayers [6]. Such experiments show the possibility of exciting speci c vibrational m odes by injecting electrons; these excitations show up as sharp features in the di erential conductance.

It has been known form any years that coupling between electrons and m olecular vibrations plays an important role in transport properties of bulk Im s of long conjugated m olecules (such as conducting and sem iconducting polymers); the transport then occurs by classical di usion of polarons or solitons [8]. The new realisation is that such e ects are also crucial in nanoscale transport through individualm olecules, even although a classical di usive m odel for the resulting com posite excitations is no longer appropriate. This new realisation has coincided with an appreciation of the importance of local heating [11], another manifestation of the coupling between electrons and phonons.

C orresponding to this experim entalprogress, theorists have increasingly been studying electron transport in the presence of local electron-phonon (e-ph) coupling in the molecule. In cases where the e-ph e ects are weak (for example, in ETS of sm all molecules, where the electron residence time on the molecule is very short), perturbation theory for the e-ph interaction can be used to interpret ETS spectra for model systems [9] and for more realistic systems s including sm all molecules on surfaces [10] and molecular wires [12]. Going beyond perturbative approximations, the e ects of e-ph coupling have been considered using scattering theory and G reen's functions approaches [13, 14, 15, 16, 17, 18, 19], using master and kinetic equations [20], and reduced density matrix approaches [21]. A nother contribution including dissipation with a sem iclassical treatment of the vibration was also developped [22]. M ore recently, approaches based on non equilibrium statistical physics have been developped for model system s [23, 24] and realistic atom ic and molecular wires [25, 26, 27].

In this paper, we describe the e ects of the coupling between in jected electrons and m olecular vibrations (both treated on the quantum level) by using a multi-channel inelastic scattering technique. We show that it is important to treat such local interactions non-perturbatively, and how our approach relates to others. In the nalpart we study the e ects of the tem perature on the conductance properties and shed some light on the basic understanding of the features observed in ETS spectra.

Note that in the following, we consider independent charge carriers interacting with single or multiple quantized vibrational modes. Calculations including the interaction between charges [28] or the interaction between charge and classical vibrations [29] have been considered elsewhere.

M odel

Before presenting some num erical results, we describe our approach to inelastic transport and its relation to other approaches.

Physicalm odel

O urm odel involves those delocalized electron states which simultaneously carry current through the molecule and interact with its eigenmodes of vibration. In the case of conjugated molecules these states are predominantly derived from the orbitals (though ourmethod can deal equally with other types of state, and there are no restrictions on the geometry or dimensionality). If the molecular vibrations are approximately harmonic, the reference Hamiltonian H₀ for the molecule is χ

$$H_0 = H_{el} + \frac{\Lambda}{l} a^{Y} a$$
 (1)

where H_{el} is the purely electronic H am iltonian and labels the eigenmodes of vibration of the isolated molecule in its equilibrium (generally neutral) charge state; a^{y} creates (a annihilates) a quantum of energy ! in mode . Note that H_{el} may, in principle, contain electron-electron interactions.

Our fundamental approximation is to consider the scattering only of single electrons or holes from the molecule. We expect this assumption to be reasonable when the interval between carrier transmission events is much greater than the transit time through the molecule [17], and provided that the applied bias does not cause significant uctuations in the occupancy of the molecular eigenstates (i.e. provided one charge state of the molecule dom inates during the transport process).

For electron transport, if the equilibrium charge state contains N electrons and \hat{D} ;N i is the N -electron ground state, we construct an electronic basis $j_i/N + 1i = c_i^y \hat{D}$;N i where the fc_i^y create an electron in a su ciently complete set of orbitals (for example, in all the low -lying -states of the molecule). For hole transport we would use j_j ;N $1i = c_j \hat{D}$;N i. We now diagonalize H el (keeping the phonon coordinates xed, for the moment) within our restricted (N 1)-electron basis to obtain a set of approximate (N 1)-electron eigenstates. U sing the electron creation (c_n^y) and annihilation (c_n) operators and the energies n, we can write

$$H_{el} = \sum_{n}^{V} c_n c_n^{V} c_n :$$
 (2)

The approximate (N 1)-electron eigenstates of the full H₀ can thus be written as \dot{p} ; fn gi, where n labels an electronic eigenstate and the fn g are occupation numbers for the vibrational modes: Y p____

$$\dot{p}; fn gi = c_n^y (a^y)^n = n! p; N; f0 gi$$
 (3)

and D;N;f0 gi is the electronic and vibrational ground state for N electrons.

The e-ph coupling term H_{eph} is taken to be linear in the phonon displacements and induces transitions between these electronic states:

$$H_{eph} = \int_{nm}^{X} (a^{y} + a) c_{n}^{y} c_{m} : \qquad (4)$$

The values of $_{n}$, ! and $_{nm}$ are calculated from a suitable model of the isolated molecule. In our work on conjugated molecules [17] we have used the Su-Schrie er-Heeger (SSH) [8] model within the harmonic limit.

To obtain the transport properties, we perform a thought experiment in which we connect the left and right ends of the molecule to metallic leads and scatter a single incoming charge carrier (electron or hole). The coupling matrix elements are $v_{L,R}$ respectively; since we do not wish to focus on the properties of the leads we take the simplest possible model for them and consider one-dimensionalsem i-in nite chains (with on-site energy $_{L,R}$ and hopping integrals $_{L,R}$, giving dispersion relations $= _{L,R} + 2 _{L,R} \cos(k_{L,R})$, where $k_{L,R}$ are dimensionalses wavevectors). We assume transport is purely elastic within the leads them selves; dissipation occurs in remote reservoirs, as in the standard Landauer picture for electron transport. The scattering states j i for a single incoming carrier are then expanded inside the molecule onto the eigenstates jn; fn gi of H₀. The single added carrier can be anywhere in the system and interacts with lattice vibrations only when inside the molecule.

The transport problem is solved by mapping the many body problem onto a single-electron one with many scattering channels [13, 15, 17]; each channel represents a process by which the electron might exchange energy with the vibration modes. For an initial mode distribution b fm g and an incoming electron from the left, the outgoing channels in the left and right leads are associated with energy-dependent rejection coecients r $_{ab}()$ and transmission coecients t $_{ab}()$, where a fn g is the nalmode distribution. In the leads, the scattering states are propagating waves with amplitudes r_{ab} (rejection) and t_{ab} (transmission), and wave vectors

corresponding to the initial $(_{in})$ and nal $(_{n})$ electronic energies. By projecting out the leads, we work entirely in the molecular subspace to obtain the scattering state j i by solving

$$\begin{bmatrix} ! & H_0 & H_{eph} & {}_{L}^{r} (!) & {}_{R}^{r} (!) \end{bmatrix} j (!) i$$

$$G^{r} (!)^{-1} j (!) i = j s_{b} (!) i:$$
(5)

Here ! is the conserved total energy;

$$! = _{in} + m ! = _{n} + n ! :$$
 (6)

The source term $j_{b_0}(!)i$ is xed by the incoming boundary conditions, while $\prod_{L,R}^{r}(!)$ are the electron self-energies arising from the coupling of the molecule to the leads. The components of the scattering states then give the matrix elements of the retarded G reen's function G^r(!). In practice, the linear system $ji = G^r j_i i$ is solved for a nite-size molecular subspace, by truncating the occupation number above a maximum n^{max} in each mode. This is physically reasonable because the injected charge cannot populate in nitely many excitations.

From the solution of Eq.(5), we can calculate any observable property, such as the expectation value of an operator A: $hAi = \int_{fbg} W_b^{ph} (T) h A j i where W_b^{ph} (T)$ is the statistical weight of the distribution b fm g of m odes at tem perature T. The transmission probability T_{ab} is given from the square of the transmission coe cients t_{ab} with the usual ratio of the electron velocities in the outgoing and incom ing channels. In our model, $t_{ab} / hi = N J_{ab}$ is and the transmission probability T_{ab} is written as [18, 19]

$$T_{ab}(n; in) = 4 \frac{v_{L}^{2}}{L} \sin k_{b}^{L}(in) \frac{v_{R}^{2}}{R} \sin k_{a}^{R}(n)$$

$$\mathfrak{h} = N \mathfrak{f} \mathfrak{f}_{ab}^{R}(!) \mathfrak{f} = \mathfrak{h} \mathfrak{f}^{2}; \qquad (7)$$

where $\ln jG_{ab}^{r}$ (!) jLi is the matrix element of the Green's function G^{r} taken between the left side i = 1 and the right side i = N of the molecule and the vibration distributions before (b) and after (a) scattering. The factors $v_{L,R}^{2} = {}_{L,R} \sin k_{b,a}^{L,R}$ are related to the imaginary parts of the retarded self-energies ${}_{L,R}^{r}$.

Two concluding notes are in order. First, this procedure solves the problem non-perturbatively in the e-ph interaction. Second, we have described the method for the case where the channel structure of the leads is generated only by the vibrational excitations of the molecule, but it is straightforward to generalize it to the case of multiple spatial channels in the leads.

Connection to other m ethods

Here we etablish how the multichannel scattering technique is related to otherm ethods based on two-particle G meen's functions for non-interacting electrons [31] and on non-equilibrium G meen's functions [24, 25, 26, 27]. We will show below (for a simplified molecular model) that G^r can be reform ulated to include the self-energies arising from the coupling of the molecule to the leads ($\frac{r}{leads}$) and from the interaction of the electron with the vibrations ($\frac{r}{eph}$).

Let us start with the generalisation of the Landauer form ula for non-equilibrium interacting system s given in Ref.[32]. In the following we consider the single-site, single-vibrationalmode (SSSM) model, which allows us to illustrate the essential physics without complicating the algebra. We rst assume that the left and right leads are identical, and couple to the molecule via energy-independent hopping integrals. Then, the self-energies $r_{L,R}$ (and their in aginary parts $r_{L,R}$) are proportional to each other. A coording to Ref.[32], the current through the junction is then given by

$$I = \frac{2e}{h}^{Z} d! (f_{L} (!) f_{R} (!)) Im Trf (!)G^{r} (!)g;$$
(8)

where $f_{L,R}$ is the Ferm i distribution of the left and right (non-interacting) lead respectively, $L_R = (L_R + R)$ and G^r is the retarded G reen's function of the molecule including the self-energies arising from the coupling to the leads and from the interaction between particles. Here we consider non-interacting charge carriers coupled to vibrations of the molecule.

W ithin the SSSM model there is only one energy level $_0$ that couples to a single mode of frequency $!_0$ with a coupling constant $_0$. For this model, G^r is the inverse of a tridiagonal matrix R in the subspace $j_n i$ of the excitations n of the vibrational mode (n = 0 is ground state of the mode) with diagonal elements $R_{nm} = ! 0 n!_0 \frac{r_{fng}}{n} (!)$ and non-zero o - diagonal elements $R_{nm+1} = 0 \frac{p}{n+1}$ and $R_{nm-1} = 0 \frac{p}{n}$. Here $\frac{r_{fng}}{r_{fng}} (!)$ is the retarded self-energy of both leads for the channel containing n phonon excitations; it is calculated by taking into account the energy conservation condition Eq.(6), which reduces in the limit of very low temperature to $! = i_n = f_{in} + n!_0$. Furthermore, in this limit, only the matrix element of G^r between the phonon ground state $G^r_{00} = h_0 j G^r (!) j_0 i$ enters in the evaluation of the current. It can be expressed as a continued fraction:

$$G_{00}^{r}(!) = [! \quad _{0} \quad _{flg}^{r}(!)$$

$${}_{0}^{2} = (! \quad _{0} \quad !_{0} \quad _{flg}^{r}(!)$$

$$2 \quad _{0}^{2} = (! \quad _{0} \quad 2! \quad _{f2g}^{r}(!)$$

$$3 \quad _{0}^{2} = (! \quad _{0} \quad 3! \quad _{f3g}^{r}(!) \quad ::::] \quad ^{1} \qquad (9)$$

The imaginary part of G $_{00}^{\rm r}$ can be rewritten as the sum of several term s:

$$\lim_{f \to g} f_{0g} + \frac{2}{100} \int_{0}^{r} \frac{1}{100} \int_{0}^{r} \frac{1}$$

A fter som e calculation, it can be shown that $\text{Im } G_{00}^r$ is actually related to the other non-diagonal elements $h_n J_r^r j_0 i$ of the G reen's function and that nally one has

$$\operatorname{Im} h_{0} \mathfrak{F}^{r} \mathfrak{j}_{0} \mathfrak{i} = \prod_{n}^{r} \mathfrak{f}_{ng} \mathfrak{f}_{n} \mathfrak{f}^{r} \mathfrak{j}_{0} \mathfrak{i} \mathfrak{f}^{r} \mathfrak{j}_{0} \mathfrak{i} \mathfrak{f}^{r} \mathfrak{j} \mathfrak{j}^{r} \mathfrak{j}_{0} \mathfrak{j}^{r} \mathfrak{j}_{0} \mathfrak{j} \mathfrak{j}^{r} \mathfrak{j}_{0} \mathfrak{j} \mathfrak{j}^{r} \mathfrak{j}_{0} \mathfrak{j} \mathfrak{j}^{r} \mathfrak{j}_{0} \mathfrak{j}^{r} \mathfrak{j}_{0} \mathfrak{j}^{r} \mathfrak{j}_{0} \mathfrak{$$

Introducing this result in Eq.(8), the current for the SSSM model is then expressed as the sum of the elastic and inelastic transmission probabilities T_{ab} (⁰;) obtained from Eq.(7).

O ne can perform a similar derivation at a nite temperature T. The current is then determined from all the diagonal matrix elements Im h $_n$ $\mathbf{\hat{g}}^r\mathbf{j}_n\mathbf{i}$ including the appropriate statistical weight W $_n^{\mathrm{ph}}$ (T) for the n-th excitation of the vibration mode. Each matrix element Im h $_n$ $\mathbf{\hat{g}}^r\mathbf{j}_n\mathbf{i}$ is related to the sum of the elastic and inelastic transmission coe cients where the vibration mode is in the n-th excited state before scattering, and in the m-th excited state afterwards.

The derivations given above can be extended to general cases in which m any electronic levels are coupled to m any vibration m odes. Then the R m atrix which de nes G^r is block-tridiagonal; the diagonal blocks correspond to purely electronic processes with constant phonon occupancy, while the o -diagonal blocks correspond to the e-ph coupling m atrix _____m. The equivalent m atrix element hf0 gG^r jf0 gi of Eq.(9) is then written as a m atrix continued fraction in the corresponding basis. The same reasoning derived above holds for calculating the current in term s elastic and inelastic transm ission probabilities T_{ab} for all tem peratures.

Now, we show how to connect Eq.(11) to the approach developed in [31]. For this, let us consider the wide-band lim it for the leads, so the lead self-energies become independent of the energy and hence of the channel considered, and are purely in aginary ${}_{n}^{r}(!)$ i = i($_{L} + _{R}$). The imaginary part of G_{00}^{r} then becomes Im $G_{00}^{r}(!) = {}_{n} \frac{1}{2}n \frac{1}{3}G^{r}j_{0}i\hat{j}$. It is convenient to work in this lim it to circum vent the problem sofband-width renorm alisation when one introduces the transform ation U that diagonalises $H = H_{0} + H_{eph} = {}_{0}C_{0}^{y}c_{0} + {}_{0}a_{0}^{y}a_{0} + {}_{0}(a_{0}^{y} + a_{0})C_{0}^{y}c_{0}$. We introduce the basis set $j_{n}i = U j_{n}i$, and obtain

$$Im \ G_{00}^{r} = \begin{pmatrix} X & X \\ & & \\$$

where $\gamma_0 = 0$ $g^2!_0$ and $g = 0=!_0$. Then, calculating the overlaps $h_n j \gamma_1 i$ between the original $j_n i$ and displaced harm onic states $j_n i$ as in [30], one ultimately nds

$$\operatorname{Im} \ G_{00}^{r}(!) = e^{2g^{2}} \frac{X^{1}}{n} \frac{g^{2n}}{n!}$$

$$X^{n}_{j=0}(1)^{j} \frac{n}{j} \frac{X^{1}}{1!} \frac{g^{21}}{1!} \frac{1}{(1-\gamma_{0})(j+1)!} e^{2}$$
(13)

Eq.(13) is just the result derived in [31] for the transmission by starting from a two-particle G reen's function description for a single resonant level coupled to a single vibration mode.

It should be noticed that the equivalence between the two approaches is only valid in the wideband limit for which the full polaron shift is obtained (i.e., $_0$ shifted by the relaxation energy

 $_0^2=!_0$). In other cases, the energy dependence of the self-energies $_{fng}^r$ plays an important role. Furtherm one when the residence time of the electron in the molecule is not long enough for the vibration to respond fully to its presence, the full relaxation is not obtained and one has an interm ediate polaron shift¹. However there are no such limitations in the multichannel scattering technique, which can treat the problem for the full parameter range (including strong e-ph coupling) | provided only that the fundam ental assumption of single-carrier transport (see the discussion follow ing Eq.(1)) remains valid.

F inally, in this section, we show how the multichannel scattering technique is related to more recent approaches based on non-equilibrium G reen's functions [23, 24, 25, 26, 27]. Such a non-equilibrium approach is more suitable when our assumption of a well-de ned reference charge state breaks down. Let us rst rewrite the retarded G reen's function in Eq.(9) as

$$G^{r}(!) = [! \quad _{0} \quad _{f_{0q}}^{r}(!) \quad _{eph}^{r}(!)]^{-1};$$
(14)

where the self-energy due to the interaction between electron and phonon is symbolically and recursively given by $r_{\rm eph}^{\rm r}(!) = r_0^2 {\rm G}^{\rm r}(!) r_0^2$. Note that by de nition [17], one has the following relation for the lead self-energy: $r_{\rm fog}^{\rm r}(!) = r_{\rm fng}^{\rm r}(!)$.

In a many-body non-equilibrium G reen's functions approach, the self-energies arising from the interaction between particles are obtained from a diagram matic perturbation expansion of the interaction and by applying the rules for the time ordering and for the evaluation of products of double-timed operators on the K eldysh contour. In principle, for a coupled e-ph system, one should include processes to all orders in the interaction to calculate self-consistently the di erent electron G reen's functions dressed by the phonons, as well as the phonon G reen's functions dressed by the electrons. This is a trem endous task to achieve for realistic system s, and so far it has only been done alm ost exactly for model system s or within some approximations for atom ic or molecular wires. Recent studies have been performed using the so-called self-consistent B om approximation [24, 25, 26, 27], in which the retarded electron self-energy due to e-ph coupling is obtained from the sum of several contributions all written in the follow ing form: $\frac{r}{eph;X|Y}$ (!) / i $\frac{2}{0}$ d! 0 D ^X (! ! 0) G ^Y (! 0), where the superscripts X ; Y r;> represents the di erent types of G reen's functions (retarded r, K eldysh greater >) for the electrons (G) and for the phonons (D).

In the following, we work with the undressed phonon G reen's functions $D_0(!)$ for which the K eldysh greater component is $D_0^>(!) = i2 (N(!) (! + !_0) + (N(!) + 1) (! !_0)), N(!)$

¹ It should be noted that no polaron shift is obtained if one makes a perturbative expansion of the e-ph coupling. ² This is a closed form for a lowest order series expansion of the e-ph self-energy equivalent to the self-consistent B om approximation [24, 25, 26, 27]. In fact the continued fraction expansion of r_{eph}^{r} includes a factor n at each level of the fraction as seen in Eq.(9). Such factors arise from applying the creation (annihilation) phonon operator on the vibrational state j_{n 1(n)} i in a multi-excitation process. The exact series expansion for r_{eph}^{r} includes higher-order terms corresponding to multiple excitations, for example: $\frac{4}{0} G^{r}$ (! !₀) G^{r} (! 2!₀) G^{r} (! !₀). A sim ilar result can be obtained by a linked cluster expansion approach.

being the Bose-Einstein distribution function. In the limit of low temperatures, simpli cations arise because then N (!) = 0. Furtherm ore by using the principle of causality and the analytic properties of G^r in the complex plane, it can be shown that the contribution $\stackrel{r}{eph}_{prr}(!) = i {}_{0}^{2} Rd! {}_{0}^{0}=2 D_{0}^{r}(! ! {}_{0}^{0})G^{r}(! {}_{0}^{0}) vanishes^{3}$. The second contribution to the self-energy is given by i ${}_{0}^{2} d! {}_{0}^{0}=2 D_{0}^{2}(! ! {}_{0}^{0})G^{r}(! {}_{0}^{0})$. At zero temperature, this is exactly the self-energy ${}_{0}^{2} G^{r}(! {}_{n}^{1})$ derived previously in Eq.(14). The nal contribution to the self-energy is ${}_{eph}_{rr}(!) / d! {}_{0}^{0} D_{0}^{r}(! {}_{0}^{0}) D_{0}^{r}(! {}_{0}^{0})$. It involves the greater electron G reen's function G² which provides inform ation about the non-equilibirum density of unoccupied states of the m olecule. G² is related to the corresponding self-energy ${}_{2}^{2} = {}_{eads}^{2} + {}_{eph}^{2}$ and the retarded and advanced G reen's functions G^{1/a} via the kinetic equation G² = G^r ${}_{2}^{2} G^{r}(! {}_{0})$ and can be neglected for weak e-ph coupling. The other terms involving ${}_{eph}^{2} = {}_{aads}^{2} G^{r}(! {}_{0})$ and can be neglected for weak e-ph coupling. The other terms involving ${}_{bads}^{2}$ are in portant; how ever their contributions become e sm all when the electronic level coupled to the vibration is o -resonance with the Ferm i levels of the leads (in the limit of zero to sm all applied bias). This is case for m olecular wires having a substantial HOM O-LUM O gap, when the Ferm i levels are pinned inside this gap.

So, the multichannel scattering technique takes into account the most important contributions to the e-ph self-energy. There are some terms arising from the Keldysh approach to transport that are not treated in the multichannel technique; how ever, as mentioned above, the generalproblem of the non-equilibrium transport is so complex that it has only been solved form odel system s and using approximations for the G reen's functions and self-energies [23, 24, 25, 26, 27].

Now that we have established how to relate the multichannel scattering technique to other widely used non-perturbative approaches for transport through e-ph coupled systems, we turn to some practical applications of the technique.

R esults

In our previous studies on long conjugated molecules [18, 17], we have already shown that the longitudinal optic phonon modes are the most strongly coupled to the injected charges. We have elucidated the mechanism s of charge injection and transport in such molecular wires. The transport is associated with the form ation and propagation of polarons in perfectly dimerized (sem iconducting) molecular wires [17]. More complex mechanisms sarise in the presence of midgap states involving the delocalisation of a soliton and polaron-soliton interactions [18].

Here we present new results for models of molecules in relation with recent experiments; namely we consider the elects of the temperature on the conductance peaks around the HOMO-LUMO gap for short molecular wires [34], and we point out the di-culties for understanding the features observed in ETS [5, 6] in terms of single vibration mode analysis. In doing so, we provide a plausible explanation for the temperature dependence of the width and shape of conductance peaks from a model system. More importantly, we show that it is crucial to treat the coupling to all the relevant vibration modes simultaneously, instead of considering one mode at a time, in order to be able to identify the origin of the features in ETS spectra.

Tem perature e ects on the conductance peaks

Here we consider the experiments performed with a mechanically controlled break junction at room temperature and at low temperature (T 30K) for polyphenylene-based molecular wires [34]. The conductance curves show a peak just above a region of very low conductance at small bias (which might be a HOMO-LUMO gap or Coulomb gap). At low temperature, the peak is asymmetric with a maximum width of 125 meV. At room temperature, this peak has a reduced amplitude and is more symmetric with a bell-like shape of maximum width 300 meV. It is clear that such a temperature dependence cannot be explained by the broadening of the

³This is always true for electron-hole-symmetric systems. It is also true when the system is not too far from equilibrium.



Figure 1: Total e ective transm ission T_e versus energy ! for the SSSM model ($_0$ 0.5 eV, ! $_0$ 80 m eV, $_0$! $_0$ =2). Left panel: Very low temperature limit: the transm ission peak (red line) is asymmetric towards higher energy because of the presence of phonon side-bands corresponding to phonon emission. The resonance peak obtained in the absence of e-ph coupling (green line) is symmetric around $_0$. Right panel: At room temperature, both phonon emission and adsorption processes are available. The transmission peak (red line) is more symmetric around $_0$ and its amplitude is reduced. In both panels, the blue lines represent the transmission obtained for a strongly reduced broadening in order to show explicitly the phonon side-bands.

Ferm i sea of the electrodes: a broadening over kT is not enough to explain the widening of the conductance peak and its change of shape. We therefore assume that there are uctuations within the junction or at the molecule-electrode contacts, and that these uctuations are related to low frequency vibration modes. It is discult to identify exactly the nature of such modes, so we consider for simplicity a SSSM model in which the single level $_0$ is coupled to a low frequency vibration mode (! $_0$ 80 meV) via a coupling constant $_0$! $_0=2$.

We perform calculations for this model according to the prescriptions given in the previous section at very low temperature and at room temperature. The total elective transmission T_e (!) is obtained as the sum of all the elastic and inelastic contributions to the transmission and is shown in Fig. 1 for the zero temperature limit (kT = 0) and for room temperature (kT !_0=2). In the absence of e-ph coupling, the transmission is given by a single symmletric resonance located around $_0$, as expected. In the presence of e-ph coupling, the shape of the transmission peak is asymmletric tow ardshigher energy. The phonon side-band peaks are located at energies above $_0$ because only phonon emission processes are allowed at low temperatures. At room temperature, both phonon emission and absorption processes become e possible and the phonon band peaks appear for energies above and below the molecular level.⁴ The transmission peak is then more symmletric around $_0$. Futhermore, its amplitude is reduced compared to the peak at T = 0, as observed experimentally.

⁴This lineshape appears similar to that obtained for very low temperature and very strong coupling [33], but the physics is quite di erent because absorption processes are important.



Figure 2: Totale ective transm ission T_e versus energy ! for a molecular wire of length N = 155. The transm ission is calculated by including a single vibration modes one at a time. Optic mode $!_1 = 112:1 \text{ meV}$ (red line) showing the most important polaron shift, $!_2 = 129:9 \text{ meV}$ (green line), $!_3 = 136:8 \text{ meV}$ (blue line). The transm ission in the absence of e-ph coupling is also show n (black line). The vertical bars represent (for the same color) the eigenvalues of the isolated molecule H am iltonian including the coupling of the single mode to the many molecular levels.

It is interesting that such a simple model provides results in qualitative agreement with the conductance measurements performed in Ref.[34]. Such a mechanism therefore provides a plausible explanation for the temperature dependence of the conductance peaks in molecular junctions, although we cannot rule out other possible explanations such as those given in Refs. [23, 24].

Multi-vibration mode e ects

We now consider a more realistic molecular wire built from an odd number N of monomers as obtained from the SSH model. In this case, there is a mid-gap state in the HOMO-LUMO gap. In the following, we couple all the unoccupied states to the low energy optic modes as in Eq.(4). The actual spatial and frequency structure of these modes is very important in allowing charge to propagate through the molecule in contrast to previous studies on simpler model systems [13].

As a generalisation of the SSSM model, there will also be phonon side-bands in the transm ission. The phonon side-band peaks related to the mid-gap state will appear inside the HOMO-LUMO gap. Such peaks also exist in the absence of the mid-gap state, i.e. for wires of even length N; how ever, there they are hidden in the background of the resonances from the molecular conduction band.

The transm ission curves for a wire of length N = 155 in which the molecular levels interact with a single vibration mode one at a time are shown in Fig2. Several di erent optic modes (! _1; _2; _3 = 112.1, 129.9, 136.8 meV) are considered. The total ective transm ission T_e shows phonon side-band peaks in the HOMO-LUMO gap, separated as expected by the corresponding



Figure 3: Totale ective transm ission T_e versus energy ! for a molecular wire of length N = 155. The transm ission (magenta line) is calculated by including the coupling to the three optic modes shown in Fig.2. New spectroscopic features appear in the transm ission. The vertical bars give the eigenvalues of the isolated molecular H am iltonian with many levels coupled to the three optic modes. The transm ission in the absence of e-ph coupling is also shown (black line) as well as the transm ission obtained for a coupling to a single mode (thin solid line) as in Fig.2.

energy ! . Up to small energy shifts due to real part of the self-energies, the peaks in the transm ission correspond to the eigenvalues of the coupled e-ph H am iltonian of the isolated m olecule, as shown by the vertical bars in Fig 2. For some eigenvalues, there are no resonances in the transm ission. There are several possible reasons for this: (i) the phonon side-band peaks associated to a given electronic transition have an exponentially decaying weight for large numbers of excitation quanta, so some of these peaks may disappear in the tail of other resonances; (ii) there m ight be destructive quantum interferences for the corresponding process⁵; (iii) the corresponding eigenstates are such that the m atrix elements hN (j_{ab}) is in Eq.(7) are small or vanishing.

Note that such calculations also reveal which optic phonon mode contributes the most to the polaron shift (shift towards lower energy of the rst resonance above the gap due to the e-ph coupling). In the present case, the optic mode of energy ! $_1 = 112.1 \text{ m eV}$ gives the most im portant polaron shift.

However for realistic molecules, the e-ph coupling matrix is non-diagonal and at the same time the injected charge may couple simultaneously to dierent vibration modes. Calculations including simultaneous coupling to the three optic modes mentioned above were performed. New spectroscopic information is obtained, as shown in Fig. 3. The transmission is not simply a superposition of the contribution of the three dierent modes shown in Fig. 2; instead, new peaks appear. These features can be interpreted in terms of quantum interferences between the dierent elastic and inelastic electron paths as well as in terms of beating e ects. All

 $^{^{5}}$ Such e ects appear more offen when several electronic levels are coupled simultaneously to several vibration modes.

these features in the transm ission correspond to the eigenvalues of the coupled e-ph m olecular H am iltonian H , provided coupling of the m any m olecular levels to the three di erent vibration m odes is included. A detailed analysis of the origins of such features is beyond the scope of the present paper; how ever, these e ects show that the general form for the e-ph coupling Eq.(4) in realistic system s creates features in the transm ission that cannot be obtained in term s of single vibration m ode analysis.

This is a very important result when one considers the interpretation of recent ETS experiments in molecular junctions⁶. Our results shown that special care is needed when assigning features in the transmission or the current to speci c vibration modes of the molecular junction. Calculations for realistic three-dimensional geometries in molecular junctions are currently under investigation.

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⁶A lthough the totale ective transm ission is not the di erential conductance of the ETS spectra, it contains the same spectroscopic inform ations of the coupled e-ph system.

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